# CEL

# 5V, SUPER MINIMOLD MEDIUM POWER SI MMIC AMPLIFIER

## **UPC2710TB**

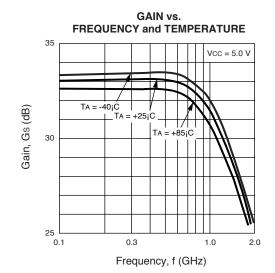
#### **FEATURES**

- HIGH DENSITY SURFACE MOUNTING:
   6 Pin Super Minimold or SOT-363 package
- HIGH GAIN: 33 dB TYP
- SATURATED OUTPUT POWER:
  - +13.5 dBm
- SUPPLY VOLTAGE: Vcc = 4.5 to 5.5 V

#### **DESCRIPTION**

NEC's UPC2710TB is a Silicon RFIC manufactured using the NESAT III process. This device is suitable as a PA driver amplifier for cellular radio and other communication receivers. The UPC2710TB is pin compatible and has comparable performance to the larger UPC2710T, so it is suitable for use as a replacement to help reduce system size. The IC is housed in a 6 pin super minimold or SOT-363 package.

NEC's stringent quality assurance and test procedures ensure the highest reliability and performance.



#### ELECTRICAL CHARACTERISTICS (TA = 25 °C, Vcc = 5 V, f = 0.5 GHz)

	PART NUMBER PACKAGE OUTLINE		UPC2710TB \$06			
SYMBOLS PARAMETERS AND CONDITIONS		UNITS	MIN	TYP	MAX	
Icc	Circuit Current (no signal)		16	22	29	
Gs	Small Signal Gain	dB	30	33	36.5	
fu	Upper Limit Operating Frequency (The gain at fu is 3 dB down from the gain at 0.1 GHz)	GHz	0.7	1.0		
ΔGs	Gain Flatness, f = 0.1 ~ 0.6 GHz f = 0.1 ~ 0.8 GHz	dB		±0.8		
PSAT	Saturated Output Power	dBm	+11	+13.5		
P1dB	Output Power at 1dB Compression Point	dBm		+7.5		
NF	Noise Figure	dB		3.5	5	
RLIN	Input Return Loss	dB	3	6		
RLOUT	Output Return Loss	dB	9	12		
ISOL	Isolation		34	39		
ΔGт	Gain -Temperature Coefficient			-0.006		
Rтн	Thermal Resistance (Junction to Ambient)	°C/W			325	

\_California Eastern Laboratories

## ABSOLUTE MAXIMUM RATINGS<sup>1</sup> (TA = 25°C)

SYMBOLS	PARAMETERS	UNITS	RATINGS
Vcc	Supply Voltage	V	6
Pin	Input Power	dBm	+10
Рт	Power Dissipation <sup>2</sup>	mW	200
Тор	Operating Temperature	°C	-40 to +85
Тѕтс	TSTG Storage Temperature		-55 to +150

# RECOMMENDED OPERATING CONDITIONS

SYMBOL	PARAMETER	UNITS	MIN	TYP	MAX
Vcc	Supply Voltage	V	4.5	5.0	5.5

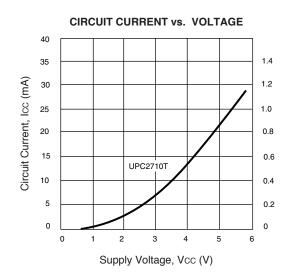
#### Notes:

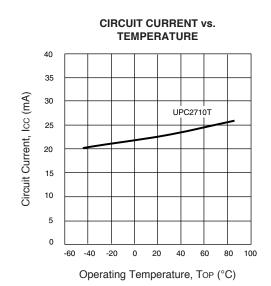
- 1. Operation in excess of any one of these parameters may result in permanent damage.
- 2. Mounted on 50 x 50 x 1.6 mm epoxy glass PWB ( $TA = +85^{\circ}C$ ).

#### **PIN DESCRIPTIONS**

Pin No.	Symbol	Applied Voltage (V)	Pin Voltage (V)	Description	Internal Equivalent Circuit
1	Input	_	0.9	Signal input pin. An internal matching circuit, configured with resistors, enables 50 $\Omega$ connection over a wide bandwidth. A multi-feedback circuit is designed to cancel the deviations of hFE and resistance. This pin must be coupled to the signal source with a blocking capacitor.	€ vcc
4	Output	_	-	Signal output pin. Connect an inductor between this pin and Vcc to supply current to the internal output transistors.	● OUT
6	Vcc	4.5 to 5.5		Power supply pin. This pin should be externally equipped with a bypass capacitor to minimize ground impedance.	(a) (b) (c) (c) (c) (c) (c) (c) (c) (c) (c) (c
2 3 5	GND	0	-	Ground pins. These pins should be connected to system ground with minimum inductance. Ground pattern on the board should be formed as wide as possible. All the ground pins must be connected together with wide ground pattern to minimize impedance difference.	UNU UNU

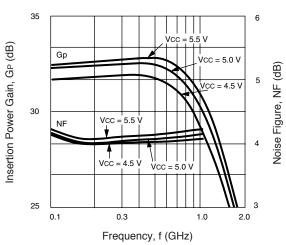
#### TYPICAL PERFORMANCE CURVES (TA = 25°C)



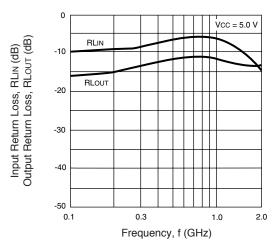


#### TYPICAL PERFORMANCE CURVES (TA = 25° C)

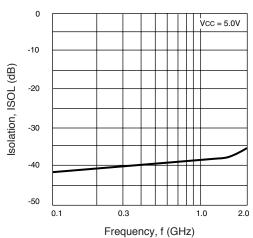
# NOISE FIGURE AND INSERTION GAIN vs. FREQUENCY



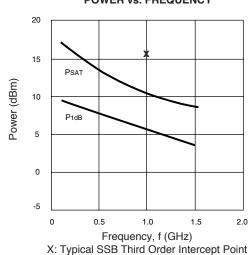
#### RETURN LOSS vs. FREQUENCY



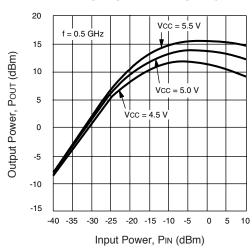
#### **ISOLATION vs. FREQUENCY**



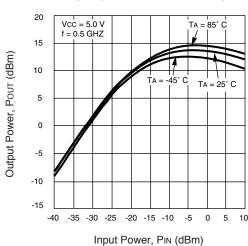
#### POWER vs. FREQUENCY



# OUTPUT POWER vs. INPUT POWER AND VOLTAGE

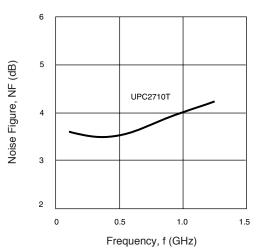


# OUTPUT POWER vs. INPUT POWER AND TEMPERATURE

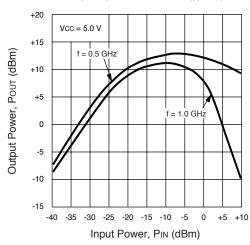


#### TYPICAL PERFORMANCE CURVES (TA = 25°C)

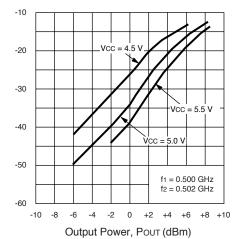
#### **NOISE FIGURE vs. FREQUENCY**



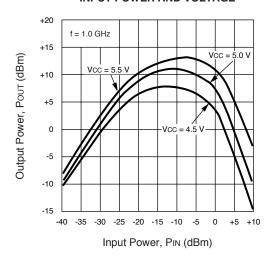
# OUTPUT POWER vs. INPUT POWER AND FREQUENCY



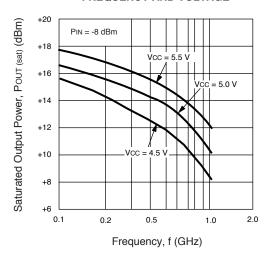
# THIRD ORDER INTERMODULATION DISTORTION vs. OUTPUT POWER OF EACH TONE and VOLTAGE



# OUTPUT POWER vs. INPUT POWER AND VOLTAGE



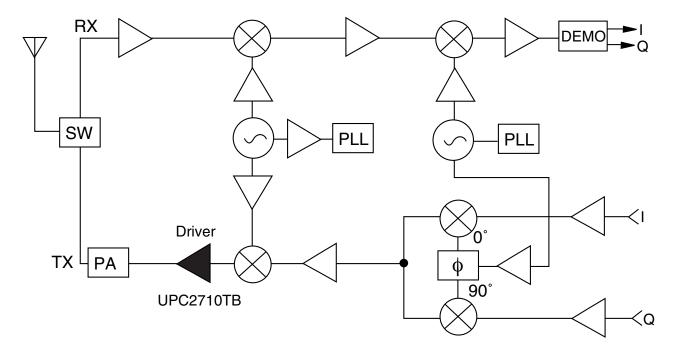
# SATURATED OUTPUT POWER vs. FREQUENCY AND VOLTAGE



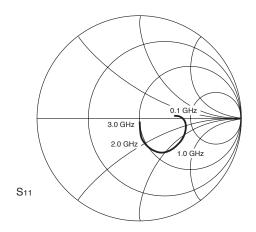
Third Order Intermodulation Distortion, IM3 (dBc)

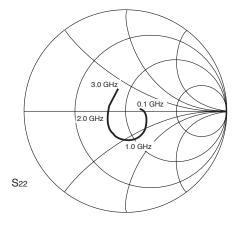
#### **SYSTEM APPLICATION EXAMPLE**

#### **Example of 900 MHz Band Digital Cellular Telephone**



## TYPICAL SCATTERING PARAMETERS $(T_A = 25^{\circ}C)$





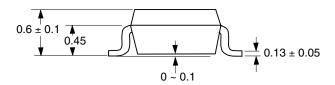
#### **UPC2710TB**

Vcc = Vout = 5 V, Icc = 22 mA

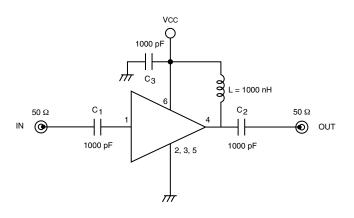
REQUENCY		S11	s	21	S1	2		S22	K
GHz	MAG	ANG	MAG	ANG	MAG	ANG	MAG	ANG	
0.1	0.306	2.5	43.072	-8.4	0.012	15.2	0.156	2.7	1.08
0.2	0.324	5.2	43.517	-17.1	0.010	10.7	0.164	2.1	1.17
0.3	0.356	5.3	44.432	-26.5	0.010	20.2	0.185	0.3	1.10
0.4	0.400	2.5	45.513	-36.9	0.012	26.9	0.225	-5.5	0.92
0.5	0.439	-3.3	45.679	-48.1	0.012	27.0	0.255	-15.4	0.85
0.6	0.469	-10.2	45.670	-59.7	0.013	31.3	0.283	-27.6	0.77
0.7	0.481	-17.9	44.793	-71.8	0.014	27.9	0.312	-54.9	0.74
8.0	0.488	-26.7	43.016	-84.3	0.014	34.9	0.301	-40.2	0.74
0.9	0.479	-34.5	40.519	-96.0	0.013	26.6	0.307	-92.2	0.85
1.0	0.465	-41.2	37.946	-107.3	0.016	30.8	0.311	-79.5	0.79
1.1	0.448	-49.3	35.122	-117.9	0.016	26.6	0.307	-92.2	0.85
1.2	0.417	-54.9	32.108	-128.0	0.015	39.5	0.282	-104.6	0.99
1.3	0.387	-61.2	29.221	-137.0	0.015	39.7	0.270	-115.5	1.12
1.4	0.350	-65.2	26.656	-145.8	0.015	50.2	0.248	-127.0	1.27
1.5	0.316	-70.8	23.895	-153.9	0.013	50.8	0.236	-136.2	1.56
1.6	0.292	-74.0	21.576	-161.6	0.016	56.6	0.215	-145.3	1.49
1.7	0.256	-76.9	19.567	-168.1	0.015	69.0	0.200	-155.2	1.71
1.8	0.245	-80.5	17.743	-174.4	0.018	61.7	0.196	-162.5	1.59
1.9	0.215	-82.9	16.040	179.6	0.017	70.0	0.180	-173.4	1.88
2.0	0.201	-85.6	14.717	173.5	0.021	71.2	0.175	-178.1	1.71
2.1	0.177	-84.4	13.475	168.8	0.020	83.0	0.166	172.0	1.94
2.2	0.161	-88.8	12.327	163.1	0.021	76.7	0.171	167.7	1.99
2.3	0.145	-88.7	11.154	158.7	0.022	87.9	0.159	159.7	2.08
2.4	0.124	-90.3	10.262	154.4	0.023	81.4	0.164	154.0	2.15
2.5	0.113	-89.8	9.490	150.4	0.025	91.9	0.158	147.0	2.19
2.6	0.107	-91.9	8.793	146.4	0.028	88.7	0.166	141.8	2.06
2.7	0.091	-92.2	8.149	142.4	0.030	93.4	0.175	135.7	2.13
2.8	0.081	-94.9	7.652	138.9	0.031	92.1	0.183	131.6	2.13
2.9	0.067	-97.4	7.134	135.1	0.031	93.0	0.191	123.4	2.26
3.0	0.055	-103.8	6.726	131.5	0.039	88.3	0.200	118.9	1.97
3.1	0.039	-95.6	6.295	128.4	0.039	89.6	0.203	111.5	2.08

#### **OUTLINE DIMENSIONS** (Units in mm)

# PACKAGE OUTLINE S06 (Top View) 2.1 ± 0.1 1.25 ± 0.1 0.65 2.0 ± 0.2 1.3 2 4 0.22 +0.10 0.22 -0.05 (All Leads)



#### **TEST CIRCUIT**



#### ORDERING INFORMATION

PART NUMBER	MARKING	QTY		
UPC2710TB-E3-A	C1F	3K/Reel		

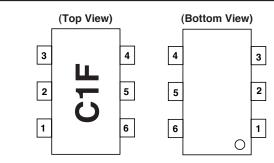
#### Note:

Embossed Tape, 8 mm wide. Pins 1, 2 and 3 face perforated side of tape.

#### Life Support Applications

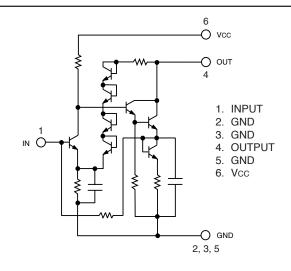
These NEC products are not intended for use in life support devices, appliances, or systems where the malfunction of these products can reasonably be expected to result in personal injury. The customers of CEL using or selling these products for use in such applications do so at their own risk and agree to fully indemnify CEL for all damages resulting from such improper use or sale.

#### **PIN CONNECTIONS**



- 1. INPUT
- 2. GND
- 3. GND
- 4. OUTPUT
- 5. GND
- 6. Vcc

#### **EQUIVALENT CIRCUIT**



EXCLUSIVE NORTH AMERICAN AGENT FOR NEC RF, MICROWAVE & OPTOELECTRONIC SEMICONDUCTORS

CALIFORNIA EASTERN LABORATORIES • Headquarters • 4590 Patrick Henry Drive • Santa Clara, CA 95054-1817 • (408) 988-3500 • Telex 34-6393 • FAX (408) 988-0279

24-Hour Fax-On-Demand: 800-390-3232 (U.S. and Canada only) • Internet: http://www.CEL.COM



4590 Patrick Henry Drive Santa Clara, CA 95054-1817 Telephone: (408) 919-2500 Facsimile: (408) 988-0279

Subject: Compliance with EU Directives

CEL certifies, to its knowledge, that semiconductor and laser products detailed below are compliant with the requirements of European Union (EU) Directive 2002/95/EC Restriction on Use of Hazardous Substances in electrical and electronic equipment (RoHS) and the requirements of EU Directive 2003/11/EC Restriction on Penta and Octa BDE.

CEL Pb-free products have the same base part number with a suffix added. The suffix –A indicates that the device is Pb-free. The –AZ suffix is used to designate devices containing Pb which are exempted from the requirement of RoHS directive (\*). In all cases the devices have Pb-free terminals. All devices with these suffixes meet the requirements of the RoHS directive.

This status is based on CEL's understanding of the EU Directives and knowledge of the materials that go into its products as of the date of disclosure of this information.

Restricted Substance per RoHS	Concentration Limit per RoHS (values are not yet fixed)	Concentration contained in CEL devices		
Lead (Pb)	< 1000 PPM	-A Not Detected	-AZ (*)	
Mercury	< 1000 PPM	Not De	etected	
Cadmium	< 100 PPM	Not Detected		
Hexavalent Chromium	< 1000 PPM	Not Detected		
PBB	< 1000 PPM	Not Detected		
PBDE < 1000 PPM		Not Detected		

If you should have any additional questions regarding our devices and compliance to environmental standards, please do not hesitate to contact your local representative.

Important Information and Disclaimer: Information provided by CEL on its website or in other communications concerting the substance content of its products represents knowledge and belief as of the date that it is provided. CEL bases its knowledge and belief on information provided by third parties and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. CEL has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. CEL and CEL suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall CEL's liability arising out of such information exceed the total purchase price of the CEL part(s) at issue sold by CEL to customer on an annual basis.

See CEL Terms and Conditions for additional clarification of warranties and liability.